Memory Coupled Compute Innovating the Next Discontinuity

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Global SAIT (Samsung Advanced Institute of Technology) Labs

- SAIT was established in 1987 as a corporate R&D Center
 - Founding Philosophy: "Boundless Research for Breakthroughs"



History of SAIT Supercomputing

Since 1992, SAIT has provided supercomputing infrastructure for all Samsung employees



Systems Architecture Lab

Vision

- To develop the most innovative technologies for future HPC and AI systems

Strategy

- To break through the memory wall by significantly increasing the memory byte/flop ratio and reducing the power per bit with memory coupled compute
- To break through the communication wall with high network byte/flop ratio utilizing memory coupled compute efficiencies and novel fabric technologies

Discontinuities

- Vectors (Cray)
- Microprocessors (Beowulf)
- Multicore, multithread (x86/ Power)
- Massive parallelism (Blue Gene)
- Heterogeneity (GPUs)
- Memory coupled compute
 - The next discontinuity
 - Innovate the future collaboratively



System Overview

Key Innovations

- Memory Coupled Compute (3D integration of memory with processors)
- Supernodes (large and high-performing globally accessible memory)
- Productive and tight-coupling of mainstream cores with accelerators
- Extreme system-level energy-efficiency

Key Goals

- HPCG performance and energy efficiency
- Green500

The Memory and Communication Wall is getting Higher



https://daydaynews.cc/en/science/the-biggest-obstacle-to-ai-training-is-not-computing-power.html

Modeling and simulation applications are memory bandwidth limited
AI, and some mod/sim, applications are communication bandwidth limited

Attacking the Memory Wall

- Put compute close to memory
 - 2.5D (Processing near memory)
 - Current technology
 - HBM co-packaged with compute
 - PIM (Processing in Memory)
 - Closest possible to memory
 - Current constraints limit functionality
 - 3D (Memory Coupled Compute)
 - Compute closer to memory than in 2.5D
 - Reduces power consumption.
 - More efficient packaging than in 2.5D

2.5D Opportunities and Challenges

- Significant improvement over DDR
 - Bandwidth is higher
 - Latency on par
- Substrate and connections can be expensive
- Requires off die connection from logic to HBM
 - Off-die signals require more power
 - Takes die area to connect the wires



PIM Opportunities and Challenges

- Most energy efficient compute
 - ALUs on same die as memory cells
 - Data movement is minimal
- The type of operations are constrained
 - ALUs reduce memory are or increase die area
- The operations are synchronous
 If conforming to JEDEC standard





HBM-PIM enabled AI engine, PCU(Programmable Computing Unit)



AXDIMM

Memory Coupled Compute

- Improves power efficiency
 - Data moves less
- Reduces latency
 - Data travels less distance
- Allows general purpose logic
- Key decisions
 - What compute
 - Just CPU? Heterogeneous?
 - Keep the programming model productive
 - How much compute
 - Provides opportunity for high B/F ratio

Closer coupling of compute with memory



e.g. 3D systolic ML accelerators in IEEE Journal on Exploratory Solid-State Computational Devices and Circuits – June 2021



Attacking the Communication Wall

- Closer coupling of compute with memory and communication
 - Cost-efficient performance and power sharing
- Memory Coupled Compute packaging → Higher Communication Performance, driving efficiency
 High point-to-point and all-to-all bandwidth
- Large supernodes with productive programming model
 - Valuable to AI models for large reductions and large data exchanges, parallel FFT



Benefits for a Classical HPC and an AI Training Application



- Y axis performance: higher is better

- Y axis time: lower is better

Standard Productive Software Stack

Application	HPC Simulation		AI / Deep Learning		Data Analysis	
Framework / App. Library	MATLAB	BLAS	TensorFlow	РуТо	rch scikit-learn	OpenHPC
Profiler / Debugger	Score-P	VAMPIR	Valgrind	GDB	ARM DDT	
Parallel Programming	OpenMP	OpenACC	SYCL	Kokkos	os MPI	
Programming Language	C/C++	Fortran	Python	Julia	Java	as base
Management	SLURM	LSF	Docker	Singula	rity Spack	
File System	DAOS/ Lustre					
Operating System	Linux / Lightweight OS					
Hardware	Γ	MCC SoC	Inter-node Connection			
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Software Innovations and Directions

- Standard productive programming model
 - Coherent shared memory within a node including potential accelerators
 - Globally accessible memory between groups of nodes
 - Exploring innovative memory models leveraging co-designed hardware mechanisms
- Scalable and efficient messaging leveraging the communication innovation
- Linux compatibility
 - Lightweight kernel for ultra scalability and high performance
- Unified control system
 - Providing single source of information and manageability
- Storage system with high bandwidth and efficient checkpoints
- Optimized AI and Big Data frameworks

The Importance of Co-Design

Goal is to build a broadly compelling MCC

Internal machine requirements represent one design point

Look to utilize input from various key architectural design points

- Traditional HPC
- Al
- Supernode connectivity
- System fabric tapering
- Etc., etc., etc..

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Innovating the Next Discontinuity

The time is right to innovate the next discontinuity

Vision: In the future memory coupled compute will be ubiquitous

Samsung is the world leader in memory and silicon technology

Well positioned to drive the vision

Integration of memory and compute will allow future optimizations
Our investigations are focused on AI and HPC systems
Come innovate the future with us

Thank You